R20

Q.P. Code: 20EE0251

Reg. No:

SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR (AUTONOMOUS)

B.Tech I Year I Semester Supplementary Examinations November-2022 BASIC ELECTRICAL & ELECTRONICS ENGINEERING

(Mechanical Engineering)

Time: 3 hours

Max. Marks: 60

(Answer all Six Units 6 X 10 = 60 Marks)

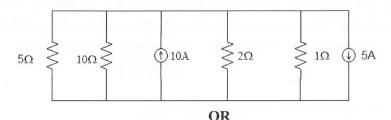
PART-A UNIT-I

1 a State and explain Ohm's law.

L1 5M

b For the given circuit as shown in figure find the voltage across 10 ohm resistor and the current passing through it.

L1 5M



2 Derive the expression of Star-Delta transformation and Delta to star transformation

L4 10M

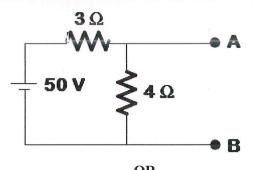
UNIT-II

3 a State Norton's theorem.

L1 2M

b Find Norton's equivalent circuit across AB for the circuit shown

L3 8M



4 Explain the principle and operation of DC generator.

L2 10M

UNIT-III

5 a Derive Torque equation of dc motor.

L3 5M

b The counter emf of Shunt motor is 227 V. The field resistance is 160Ω and field current 1.5A. If the line current is 36.5A, find the armature resistance also find armature current when the motor is stationary.

L5 5M

OR

6 a Explain constructional details of transformer.

L2 6M

b A 20 kVA, 2000/200V, 50Hz transformer has 66 secondary turns. Calculate the number of primary turns and primary and secondary currents. Neglect losses.

PART-B

UNIT-IV		
a What is Doping? Describe P-and N-type semiconductors.	L1	5M
b Explain about diffusion current with expressions.	L2	5M
OR		
a Draw the circuit diagram of a full wave rectifier and explain its operation.	L1	5M
b Define 'Ripple Factor' and derive an expression for ripple factor of a full wave Rectifier.	L1	5M
UNIT-V		
Draw the circuit diagram of an CE configuration and describe its input and output characteristics.	L1	10M
OR		
a Give the relationship between α , β and Υ of a Transistor.	L2	5M
b A transistor operating in CB configuration has IC = 2.98 mA, IE = 3.00 mA and ICO = 0.01 mA What current will flow in the collector circuit for this transistor when connected in CE configuration with a base current of 30μ A.	L1	5M
UNIT-VI		
a Classify the types of JFET and Draw its symbols.	L2	4M
b Describe the working principle of N-channel JFET. OR	L2	6M
With the help of neat diagram, explain the operation and characteristics of N-channel	L2	10M
	 a What is Doping? Describe P-and N-type semiconductors. b Explain about diffusion current with expressions. OR a Draw the circuit diagram of a full wave rectifier and explain its operation. b Define 'Ripple Factor' and derive an expression for ripple factor of a full wave Rectifier. UNIT-V Draw the circuit diagram of an CE configuration and describe its input and output characteristics. OR a Give the relationship between α, β and Υ of a Transistor. b A transistor operating in CB configuration has IC = 2.98mA, IE = 3.00 mA and ICO =0.01mA What current will flow in the collector circuit for this transistor when connected in CE configuration with a base current of 30μA. UNIT-VI a Classify the types of JFET and Draw its symbols. b Describe the working principle of N-channel JFET. OR 	 a What is Doping? Describe P-and N-type semiconductors. b Explain about diffusion current with expressions. a Draw the circuit diagram of a full wave rectifier and explain its operation. b Define 'Ripple Factor' and derive an expression for ripple factor of a full wave Rectifier. UNIT-V Draw the circuit diagram of an CE configuration and describe its input and output characteristics. OR a Give the relationship between α, β and Y of a Transistor. b A transistor operating in CB configuration has IC = 2.98mA, IE = 3.00 mA and ICO =0.01mA What current will flow in the collector circuit for this transistor when connected in CE configuration with a base current of 30μA. UNIT-VI a Classify the types of JFET and Draw its symbols. b Describe the working principle of N-channel JFET. L2 OR

Depletion type MOSFET under Enhancement mode.